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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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LN58

GaAs Infrared Light Emitting Diode

For optical control systems

■ Features

- High-power output, high-efficiency: P_O = 3.5 mW (typ.)
- Emitted light spectrum suited for silicon photodetectors
- Infrared light emission close to monochromatic light: $\lambda_P = 950 \text{ nm}$ (typ.)
- Small size, thin side-view type package

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Power dissipation	P_{D}	75	mW	
Forward current	I_{F}	50	mA	
Pulse forward current *	I_{FP}	1	A	
Reverse voltage	V _R	3	V	
Operating ambient temperature	T _{opr}	-25 to +85	°C	
Storage temperature	T _{stg}	-30 to +100	°C	

Note) *: f = 100 Hz, Duty cycle = 0.1%

■ Electro-Optical Characteristics $T_a = 25$ °C±3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Radiant power *	P _O	$I_F = 50 \text{ mA}$	1.8	3.5		mW
Reverse current	I_R	$V_R = 3 V$			10	μΑ
Forward voltage	V _F	$I_F = 50 \text{ mA}$			1.5	V
Terminal capacitance	Ct	$V_R = 0 V, f = 1 MHz$		35		pF
Peak emission wavelength	$\lambda_{ m P}$	$I_F = 50 \text{ mA}$		950		nm
Spectral half band width	Δλ	$I_F = 50 \text{ mA}$		50		nm
Half-power angle	θ	The angle when the radiant power is halved.		35		0

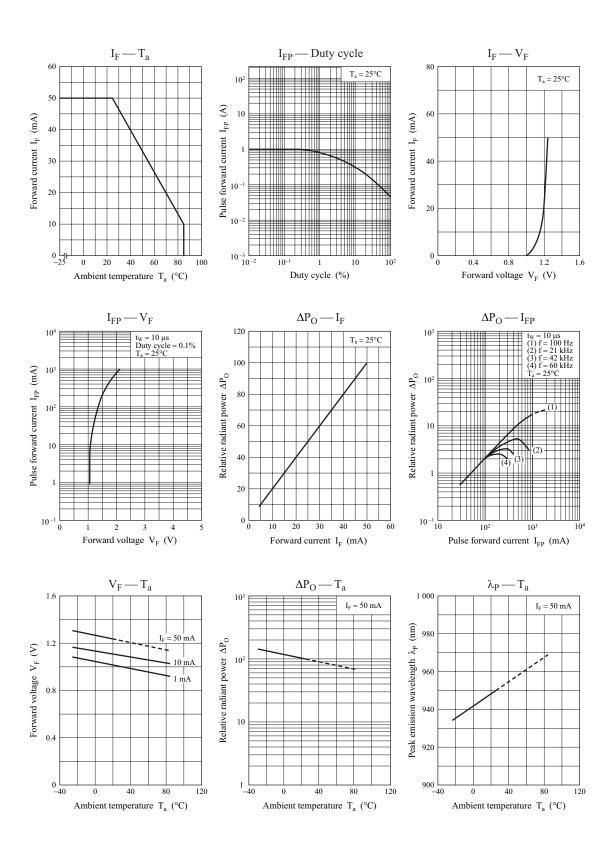
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. Cutoff frequency: 1 MHz

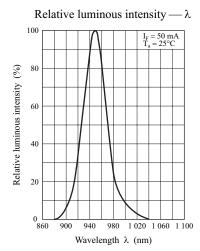
$$f_C: 10 \times log \frac{P_O \text{ at } f = f_C}{P_O \text{ at } f = 50 \text{ kHz}} = -3$$

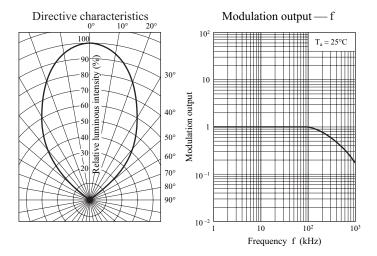
3. *: A light detection element uses a silicon diode have proofread a load with a standard device.

LN58 Panasonic



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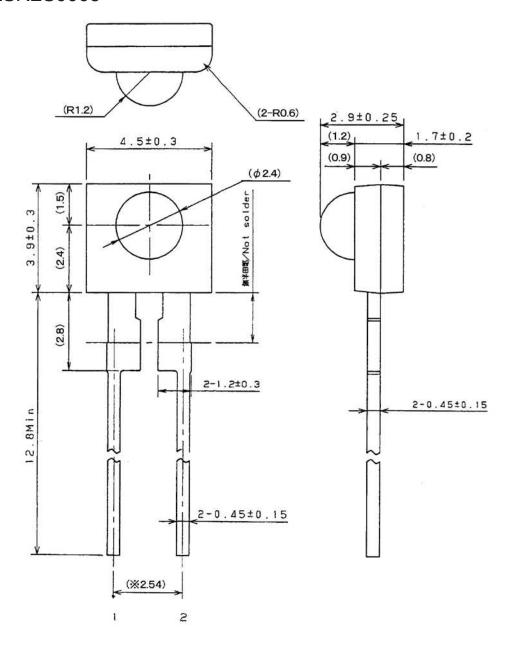




LN58 Panasonic

■ Package (Unit: mm)

LETLSN2S0003



- Pin name
 - 1: Cathode
 - 2: Anode

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